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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

| | |
|----------------------------|---|
| Product Status | Active |
| Core Processor | RL78 |
| Core Size | 16-Bit |
| Speed | 32MHz |
| Connectivity | CSI, I ² C, LINbus, UART/USART |
| Peripherals | DMA, LVD, POR, PWM, WDT |
| Number of I/O | 34 |
| Program Memory Size | 128KB (128K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | 8K x 8 |
| RAM Size | 12K x 8 |
| Voltage - Supply (Vcc/Vdd) | 1.6V ~ 5.5V |
| Data Converters | A/D 10x8/10b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 85°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 48-LQFP |
| Supplier Device Package | 48-LFQFP (7x7) |
| Purchase URL | https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100ggafb-30 |

Table 1-1. List of Ordering Part Numbers

(1/12)

| Pin count | Package | Data flash | Fields of Application ^{Note} | Ordering Part Number |
|-----------|---|-------------|---------------------------------------|--|
| 20 pins | 20-pin plastic LSSOP (7.62 mm (300), 0.65 mm pitch) | Mounted | A | R5F1006AASP#V0, R5F1006CASP#V0, R5F1006DASP#V0, R5F1006EASP#V0 R5F1006AASP#X0, R5F1006CASP#X0, R5F1006DASP#X0, R5F1006EASP#X0 |
| | | | D | R5F1006ADSP#V0, R5F1006CDSP#V0, R5F1006DDSP#V0, R5F1006EDSP#V0 R5F1006ADSP#X0, R5F1006CDSP#X0, R5F1006DDSP#X0, R5F1006EDSP#X0 |
| | | | G | R5F1006AGSP#V0, R5F1006CGSP#V0, R5F1006DGSP#V0, R5F1006EGSP#V0 R5F1006AGSP#X0, R5F1006CGSP#X0, R5F1006DGSP#X0, R5F1006EGSP#X0 |
| | | Not mounted | A | R5F1016AASP#V0, R5F1016CASP#V0, R5F1016DASP#V0, R5F1016EASP#V0 R5F1016AASP#X0, R5F1016CASP#X0, R5F1016DASP#X0, R5F1016EASP#X0 |
| | | | D | R5F1016ADSP#V0, R5F1016CDSP#V0, R5F1016DDSP#V0, R5F1016EDSP#V0 R5F1016ADSP#X0, R5F1016CDSP#X0, R5F1016DDSP#X0, R5F1016EDSP#X0 |
| | | | G | R5F1016AGSP#V0, R5F1016CGSP#V0, R5F1016DGSP#V0, R5F1016EGSP#V0 R5F1016AGSP#X0, R5F1016CGSP#X0, R5F1016DGSP#X0, R5F1016EGSP#X0 |
| 24 pins | 24-pin plastic HWQFN (4 × 4mm, 0.5 mm pitch) | Mounted | A | R5F1007AANA#U0, R5F1007CANA#U0, R5F1007DANA#U0, R5F1007EANA#U0 R5F1007AANA#W0, R5F1007CANA#W0, R5F1007DANA#W0, R5F1007EANA#W0 |
| | | | D | R5F1007ADNA#U0, R5F1007CDNA#U0, R5F1007DDNA#U0, R5F1007EDNA#U0 R5F1007ADNA#W0, R5F1007CDNA#W0, R5F1007DDNA#W0, R5F1007EDNA#W0 |
| | | | G | R5F1007AGNA#U0, R5F1007CGNA#U0, R5F1007DGNA#U0, R5F1007EGNA#U0 R5F1007AGNA#W0, R5F1007CGNA#W0, R5F1007DGNA#W0, R5F1007EGNA#W0 |
| | | Not mounted | A | R5F1017AANA#U0, R5F1017CANA#U0, R5F1017DANA#U0, R5F1017EANA#U0 R5F1017AANA#W0, R5F1017CANA#W0, R5F1017DANA#W0, R5F1017EANA#W0 |
| | | | D | R5F1017ADNA#U0, R5F1017CDNA#U0, R5F1017DDNA#U0, R5F1017EDNA#U0 R5F1017ADNA#W0, R5F1017CDNA#W0, R5F1017DDNA#W0, R5F1017EDNA#W0 |
| | | | G | R5F1017AGNA#U0, R5F1017CGNA#U0, R5F1017DGNA#U0, R5F1017EGNA#U0 R5F1017AGNA#W0, R5F1017CGNA#W0, R5F1017DGNA#W0, R5F1017EGNA#W0 |

Note For the fields of application, refer to **Figure 1-1 Part Number, Memory Size, and Package of RL78/G13**.

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

Table 1-1. List of Ordering Part Numbers

(6/12)

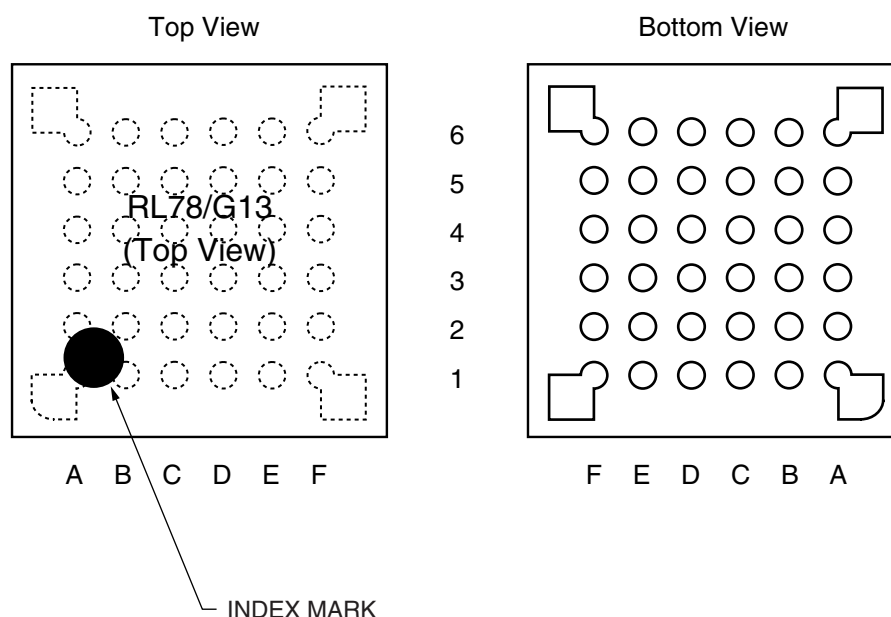
| Pin count | Package | Data flash | Fields of Application Note | Ordering Part Number |
|-----------|---|----------------|-------------------------------|---|
| 48 pins | 48-pin plastic HWQFN (7 × 7 mm, 0.5 mm pitch) | Mounted | A | R5F100GAANA#U0, R5F100GCANA#U0, R5F100GDANA#U0, R5F100GEANA#U0, R5F100GFANA#U0, R5F100GGANA#U0, R5F100GHANA#U0, R5F100GJANA#U0, R5F100GKANA#U0, R5F100GLANA#U0 R5F100GAANA#W0, R5F100GCANA#W0, R5F100GDANA#W0, R5F100GEANA#W0, R5F100GFANA#W0, R5F100GGANA#W0, R5F100GHANA#W0, R5F100GJANA#W0, R5F100GKANA#W0, R5F100GLANA#W0 |
| | | Not mounted | D | R5F100GADNA#U0, R5F100GCDNA#U0, R5F100GDDNA#U0, R5F100GEDNA#U0, R5F100GFDNA#U0, R5F100GGDNA#U0, R5F100GHDNA#U0, R5F100GJDNA#U0, R5F100GKDNA#U0, R5F100GLDNA#U0 R5F100GADNA#W0, R5F100GCDNA#W0, R5F100GDDNA#W0, R5F100GEDNA#W0, R5F100GFDNA#W0, R5F100GGDNA#W0, R5F100GHDNA#W0, R5F100GJDNA#W0, R5F100GKDNA#W0, R5F100GLDNA#W0 |
| | | | G | R5F100GAGNA#U0, R5F100GCGNA#U0, R5F100GDGNA#U0, R5F100GEGNA#U0, R5F100GFGNA#U0, R5F100GGGNA#U0, R5F100GHGNA#U0, R5F100GJGNA#U0 R5F100GAGNA#W0, R5F100GCGNA#W0, R5F100GDGNA#W0, R5F100GEGNA#W0, R5F100GFGNA#W0, R5F100GGGNA#W0, R5F100GHGNA#W0, R5F100GJGNA#W0 |
| 48 pins | 48-pin plastic HWQFN (7 × 7 mm, 0.5 mm pitch) | Not mounted | A | R5F101GAANA#U0, R5F101GCANA#U0, R5F101GDANA#U0, R5F101GEANA#U0, R5F101GFANA#U0, R5F101GGANA#U0, R5F101GHANA#U0, R5F101GJANA#U0, R5F101GKANA#U0, R5F101GLANA#U0 R5F101GAANA#W0, R5F101GCANA#W0, R5F101GDANA#W0, R5F101GEANA#W0, R5F101GFANA#W0, R5F101GGANA#W0, R5F101GHANA#W0, R5F101GJANA#W0, R5F101GKANA#W0, R5F101GLANA#W0 |
| | | | D | R5F101GADNA#U0, R5F101GCDNA#U0, R5F101GDDNA#U0, R5F101GEDNA#U0, R5F101GFDNA#U0, R5F101GGDNA#U0, R5F101GHDNA#U0, R5F101GJDNA#U0, R5F101GKDNA#U0, R5F101GLDNA#U0 R5F101GADNA#W0, R5F101GCDNA#W0, R5F101GDDNA#W0, R5F101GEDNA#W0, R5F101GFDNA#W0, R5F101GGDNA#W0, R5F101GHDNA#W0, R5F101GJDNA#W0, R5F101GKDNA#W0, R5F101GLDNA#W0 |

Note For the fields of application, refer to **Figure 1-1 Part Number, Memory Size, and Package of RL78/G13**.

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

1.3.6 36-pin products

- 36-pin plastic WFLGA (4 × 4 mm, 0.5 mm pitch)



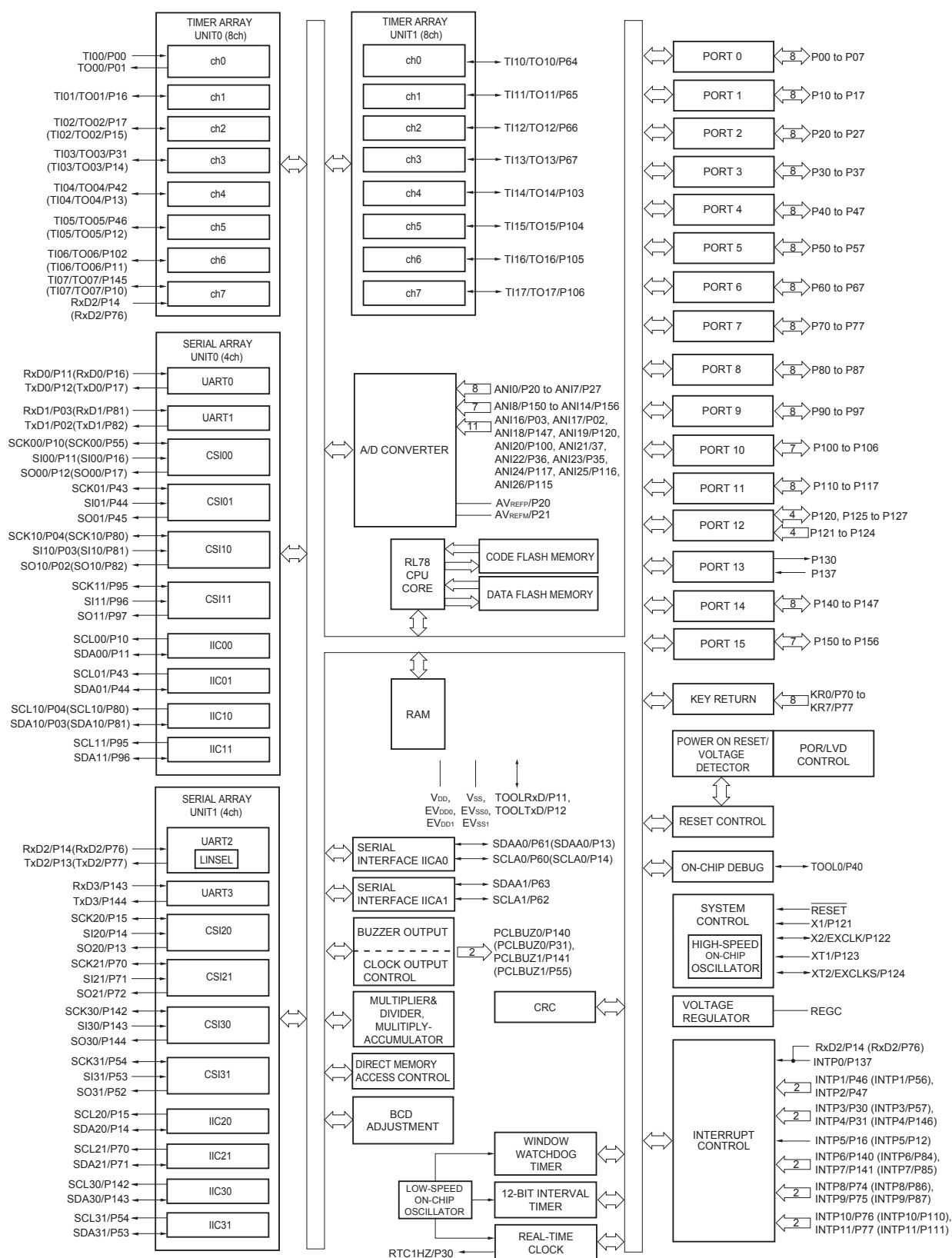
| | A | B | C | D | E | F | |
|---|---------------------------|--------------------------------|---|---|---------------------------------|---------------------------------|---|
| 6 | P60/SCLA0 | V _{DD} | P121/X1 | P122/X2/EXCLK | P137/INTP0 | P40/TOOL0 | 6 |
| 5 | P62 | P61/SDAA0 | V _{SS} | REGC | RESET | P120/ANI19 | 5 |
| 4 | P72/SO21 | P71/SI21/ SDA21 | P14/RxD2/SI20/ SDA20/(SCLA0) /(TI03)/(TO03) | P31/TI03/TO03/ INTP4/ PCLBUZ0 | P00/TI00/TxD1 | P01/TO00/RxD1 | 4 |
| 3 | P50/INTP1/ SI11/SDA11 | P70/SCK21/ SCL21 | P15/PCLBUZ1/ SCK20/SCL20/ (TI02)/(TO02) | P22/ANI2 | P20/ANI0/ AV _{REFP} | P21/ANI1/ AV _{REFM} | 3 |
| 2 | P30/INTP3/ SCK11/SCL11 | P16/TI01/TO01/ INTP5/(RxD0) | P12/SO00/ TxD0/TOOLTxD /(TI05)/(TO05) | P11/SI00/RxD0/ TOOLRxD/ SDA00/(TI06)/ (TO06) | P24/ANI4 | P23/ANI3 | 2 |
| 1 | P51/INTP2/ SO11 | P17/TI02/TO02/ (TxD0) | P13/TxD2/ SO20/(SDAA0)/ (TI04)/(TO04) | P10/SCK00/ SCL00/(TI07)/ (TO07) | P147/ANI18 | P25/ANI5 | 1 |
| | A | B | C | D | E | F | |

Caution Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μF).

Remarks 1. For pin identification, see 1.4 Pin Identification.

- Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

1.5.14 128-pin products



Remark Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

[80-pin, 100-pin, 128-pin products]

Caution This outline describes the functions at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

(1/2)

| Item | | 80-pin | | 100-pin | | 128-pin | |
|------------------------------------|--|---|----------|--|----------|---|----------|
| | | R5F100Mx | R5F101Mx | R5F100Px | R5F101Px | R5F100Sx | R5F101Sx |
| Code flash memory (KB) | | 96 to 512 | | 96 to 512 | | 192 to 512 | |
| Data flash memory (KB) | | 8 | — | 8 | — | 8 | — |
| RAM (KB) | | 8 to 32 ^{Note 1} | | 8 to 32 ^{Note 1} | | 16 to 32 ^{Note 1} | |
| Address space | | 1 MB | | | | | |
| Main system clock | High-speed system clock | X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (High-speed main) mode: 1 to 20 MHz (V _{DD} = 2.7 to 5.5 V), HS (High-speed main) mode: 1 to 16 MHz (V _{DD} = 2.4 to 5.5 V), LS (Low-speed main) mode: 1 to 8 MHz (V _{DD} = 1.8 to 5.5 V), LV (Low-voltage main) mode: 1 to 4 MHz (V _{DD} = 1.6 to 5.5 V) | | | | | |
| | High-speed on-chip oscillator | HS (High-speed main) mode: 1 to 32 MHz (V _{DD} = 2.7 to 5.5 V), HS (High-speed main) mode: 1 to 16 MHz (V _{DD} = 2.4 to 5.5 V), LS (Low-speed main) mode: 1 to 8 MHz (V _{DD} = 1.8 to 5.5 V), LV (Low-voltage main) mode: 1 to 4 MHz (V _{DD} = 1.6 to 5.5 V) | | | | | |
| Subsystem clock | | XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz | | | | | |
| Low-speed on-chip oscillator | | 15 kHz (TYP.) | | | | | |
| General-purpose register | | (8-bit register × 8) × 4 banks | | | | | |
| Minimum instruction execution time | | 0.03125 μs (High-speed on-chip oscillator: f _{IH} = 32 MHz operation) | | | | | |
| | | 0.05 μs (High-speed system clock: f _{MX} = 20 MHz operation) | | | | | |
| | | 30.5 μs (Subsystem clock: f _{SUB} = 32.768 kHz operation) | | | | | |
| Instruction set | | <ul style="list-style-type: none">• Data transfer (8/16 bits)• Adder and subtractor/logical operation (8/16 bits)• Multiplication (8 bits × 8 bits)• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc. | | | | | |
| I/O port | Total | 74 | | 92 | | 120 | |
| | CMOS I/O | 64 (N-ch O.D. I/O [E _{VDD} withstand voltage]: 21) | | 82 (N-ch O.D. I/O [E _{VDD} withstand voltage]: 24) | | 110 (N-ch O.D. I/O [E _{VDD} withstand voltage]: 25) | |
| | CMOS input | 5 | | 5 | | 5 | |
| | CMOS output | 1 | | 1 | | 1 | |
| | N-ch O.D. I/O (withstand voltage: 6 V) | 4 | | 4 | | 4 | |
| Timer | 16-bit timer | 12 channels | | 12 channels | | 16 channels | |
| | Watchdog timer | 1 channel | | 1 channel | | 1 channel | |
| | Real-time clock (RTC) | 1 channel | | 1 channel | | 1 channel | |
| | 12-bit interval timer (IT) | 1 channel | | 1 channel | | 1 channel | |
| | Timer output | 12 channels (PWM outputs: 10 ^{Note 2}) | | 12 channels (PWM outputs: 10 ^{Note 2}) | | 16 channels (PWM outputs: 14 ^{Note 2}) | |
| | RTC output | 1 channel • 1 Hz (subsystem clock: f _{SUB} = 32.768 kHz) | | | | | |

Notes 1. The flash library uses RAM in self-programming and rewriting of the data flash memory.

The target products and start address of the RAM areas used by the flash library are shown below.

R5F100xJ, R5F101xJ (x = M, P): Start address FAF00H

R5F100xL, R5F101xL (x = M, P, S): Start address F7F00H

For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

(T_A = -40 to +85°C, 1.6 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V) (3/5)

| Items | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------|------------------|--|---|----------------------|----------------------|------|
| Input voltage, high | V _{IH1} | P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147 | Normal input buffer | 0.8EV _{DD0} | EV _{DD0} | V |
| | V _{IH2} | P01, P03, P04, P10, P11, P13 to P17, P43, P44, P53 to P55, P80, P81, P142, P143 | TTL input buffer 4.0 V ≤ EV _{DD0} ≤ 5.5 V | 2.2 | EV _{DD0} | V |
| | | | TTL input buffer 3.3 V ≤ EV _{DD0} < 4.0 V | 2.0 | EV _{DD0} | V |
| | | | TTL input buffer 1.6 V ≤ EV _{DD0} < 3.3 V | 1.5 | EV _{DD0} | V |
| | V _{IH3} | P20 to P27, P150 to P156 | 0.7V _{DD} | | V _{DD} | V |
| | V _{IH4} | P60 to P63 | 0.7EV _{DD0} | | 6.0 | V |
| | V _{IH5} | P121 to P124, P137, EXCLK, EXCLKS, RESET | 0.8V _{DD} | | V _{DD} | V |
| Input voltage, low | V _{IL1} | P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P140 to P147 | Normal input buffer | 0 | 0.2EV _{DD0} | V |
| | V _{IL2} | P01, P03, P04, P10, P11, P13 to P17, P43, P44, P53 to P55, P80, P81, P142, P143 | TTL input buffer 4.0 V ≤ EV _{DD0} ≤ 5.5 V | 0 | 0.8 | V |
| | | | TTL input buffer 3.3 V ≤ EV _{DD0} < 4.0 V | 0 | 0.5 | V |
| | | | TTL input buffer 1.6 V ≤ EV _{DD0} < 3.3 V | 0 | 0.32 | V |
| | V _{IL3} | P20 to P27, P150 to P156 | 0 | | 0.3V _{DD} | V |
| | V _{IL4} | P60 to P63 | 0 | | 0.3EV _{DD0} | V |
| | V _{IL5} | P121 to P124, P137, EXCLK, EXCLKS, RESET | 0 | | 0.2V _{DD} | V |

Caution The maximum value of V_{IH} of pins P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 is EV_{DD0}, even in the N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

2.4 AC Characteristics

(T_A = -40 to +85°C, 1.6 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V)

| Items | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|---------------------------------------|--|-----------------------------------|-----------------------------------|---------|------|--------------------|
| Instruction cycle (minimum instruction execution time) | T _{CY} | Main system clock (f _{MAIN}) operation | HS (high-speed main) mode | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0.03125 | 1 | μs |
| | | | | 2.4 V ≤ V _{DD} < 2.7 V | 0.0625 | 1 | μs |
| | | | LS (low-speed main) mode | 1.8 V ≤ V _{DD} ≤ 5.5 V | 0.125 | 1 | μs |
| | | | LV (low-voltage main) mode | 1.6 V ≤ V _{DD} ≤ 5.5 V | 0.25 | 1 | μs |
| | | Subsystem clock (f _{SUB}) operation | | 1.8 V ≤ V _{DD} ≤ 5.5 V | 28.5 | 30.5 | 31.3 μs |
| | | In the self programming mode | HS (high-speed main) mode | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0.03125 | 1 | μs |
| | | | | 2.4 V ≤ V _{DD} < 2.7 V | 0.0625 | 1 | μs |
| | | | LS (low-speed main) mode | 1.8 V ≤ V _{DD} ≤ 5.5 V | 0.125 | 1 | μs |
| | | | LV (low-voltage main) mode | 1.8 V ≤ V _{DD} ≤ 5.5 V | 0.25 | 1 | μs |
| External system clock frequency | f _{EX} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 1.0 | | 20.0 | MHz |
| | | 2.4 V ≤ V _{DD} < 2.7 V | | 1.0 | | 16.0 | MHz |
| | | 1.8 V ≤ V _{DD} < 2.4 V | | 1.0 | | 8.0 | MHz |
| | | 1.6 V ≤ V _{DD} < 1.8 V | | 1.0 | | 4.0 | MHz |
| | f _{EXS} | | | 32 | | 35 | kHz |
| External system clock input high-level width, low-level width | t _{EXH} , t _{EXL} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 24 | | | ns |
| | | 2.4 V ≤ V _{DD} < 2.7 V | | 30 | | | ns |
| | | 1.8 V ≤ V _{DD} < 2.4 V | | 60 | | | ns |
| | | 1.6 V ≤ V _{DD} < 1.8 V | | 120 | | | ns |
| | t _{EXHS} , t _{EXLS} | | | 13.7 | | | μs |
| Ti00 to Ti07, Ti10 to Ti17 input high-level width, low-level width | t _{TIH} , t _{TIL} | | | 1/f _{MCK} +10 | | | ns ^{Note} |
| TO00 to TO07, TO10 to TO17 output frequency | f _{TO} | HS (high-speed main) mode | | 4.0 V ≤ EV _{DD0} ≤ 5.5 V | | 16 | MHz |
| | | | | 2.7 V ≤ EV _{DD0} < 4.0 V | | 8 | MHz |
| | | | | 1.8 V ≤ EV _{DD0} < 2.7 V | | 4 | MHz |
| | | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | 2 | MHz |
| | | LS (low-speed main) mode | | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | 4 | MHz |
| | | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | 2 | MHz |
| | | LV (low-voltage main) mode | | 1.6 V ≤ EV _{DD0} ≤ 5.5 V | | 2 | MHz |
| PCLBUZ0, PCLBUZ1 output frequency | f _{PCL} | HS (high-speed main) mode | | 4.0 V ≤ EV _{DD0} ≤ 5.5 V | | 16 | MHz |
| | | | | 2.7 V ≤ EV _{DD0} < 4.0 V | | 8 | MHz |
| | | | | 1.8 V ≤ EV _{DD0} < 2.7 V | | 4 | MHz |
| | | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | 2 | MHz |
| | | LS (low-speed main) mode | | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | 4 | MHz |
| | | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | 2 | MHz |
| | | LV (low-voltage main) mode | | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | 4 | MHz |
| | | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | 2 | MHz |
| Interrupt input high-level width, low-level width | t _{INTH} , t _{INTL} | INTP0 | 1.6 V ≤ V _{DD} ≤ 5.5 V | 1 | | | μs |
| | | INTP1 to INTP11 | 1.6 V ≤ EV _{DD0} ≤ 5.5 V | 1 | | | μs |
| Key interrupt input low-level width | t _{KR} | KR0 to KR7 | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | 250 | | | ns |
| | | | 1.6 V ≤ EV _{DD0} < 1.8 V | 1 | | | μs |
| RESET low-level width | t _{RSL} | | | 10 | | | μs |

(Note and Remark are listed on the next page.)

(3) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)

(T_A = -40 to +85°C, 1.6 V ≤ E_{VDD0} = E_{VDD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = E_{VSS0} = E_{VSS1} = 0 V)

| Parameter | Symbol | Conditions | | HS (high-speed main) Mode | | LS (low-speed main) Mode | | LV (low-voltage main) Mode | | Unit |
|---|--|--|-----------------------------------|----------------------------|------|----------------------------|------|----------------------------|------|------|
| | | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 4/f _{CLK} | 2.7 V ≤ E _{VDD0} ≤ 5.5 V | 125 | | 500 | | 1000 | | ns |
| | | | 2.4 V ≤ E _{VDD0} ≤ 5.5 V | 250 | | 500 | | 1000 | | ns |
| | | | 1.8 V ≤ E _{VDD0} ≤ 5.5 V | 500 | | 500 | | 1000 | | ns |
| | | | 1.7 V ≤ E _{VDD0} ≤ 5.5 V | 1000 | | 1000 | | 1000 | | ns |
| | | | 1.6 V ≤ E _{VDD0} ≤ 5.5 V | — | | 1000 | | 1000 | | ns |
| SCKp high-/low-level width | t _{KH1} , t _{KL1} | 4.0 V ≤ E _{VDD0} ≤ 5.5 V | | t _{KCY1} /2 – 12 | | t _{KCY1} /2 – 50 | | t _{KCY1} /2 – 50 | | ns |
| | | 2.7 V ≤ E _{VDD0} ≤ 5.5 V | | t _{KCY1} /2 – 18 | | t _{KCY1} /2 – 50 | | t _{KCY1} /2 – 50 | | ns |
| | | 2.4 V ≤ E _{VDD0} ≤ 5.5 V | | t _{KCY1} /2 – 38 | | t _{KCY1} /2 – 50 | | t _{KCY1} /2 – 50 | | ns |
| | | 1.8 V ≤ E _{VDD0} ≤ 5.5 V | | t _{KCY1} /2 – 50 | | t _{KCY1} /2 – 50 | | t _{KCY1} /2 – 50 | | ns |
| | | 1.7 V ≤ E _{VDD0} ≤ 5.5 V | | t _{KCY1} /2 – 100 | | t _{KCY1} /2 – 100 | | t _{KCY1} /2 – 100 | | ns |
| | | 1.6 V ≤ E _{VDD0} ≤ 5.5 V | | — | | t _{KCY1} /2 – 100 | | t _{KCY1} /2 – 100 | | ns |
| Slp setup time (to SCKp↑) <small>Note 1</small> | t _{SIK1} | 4.0 V ≤ E _{VDD0} ≤ 5.5 V | | 44 | | 110 | | 110 | | ns |
| | | 2.7 V ≤ E _{VDD0} ≤ 5.5 V | | 44 | | 110 | | 110 | | ns |
| | | 2.4 V ≤ E _{VDD0} ≤ 5.5 V | | 75 | | 110 | | 110 | | ns |
| | | 1.8 V ≤ E _{VDD0} ≤ 5.5 V | | 110 | | 110 | | 110 | | ns |
| | | 1.7 V ≤ E _{VDD0} ≤ 5.5 V | | 220 | | 220 | | 220 | | ns |
| | | 1.6 V ≤ E _{VDD0} ≤ 5.5 V | | — | | 220 | | 220 | | ns |
| Slp hold time (from SCKp↑) <small>Note 2</small> | t _{KSI1} | 1.7 V ≤ E _{VDD0} ≤ 5.5 V | | 19 | | 19 | | 19 | | ns |
| | | 1.6 V ≤ E _{VDD0} ≤ 5.5 V | | — | | 19 | | 19 | | ns |
| Delay time from SCKp↓ to SOp output <small>Note 3</small> | t _{KSO1} | 1.7 V ≤ E _{VDD0} ≤ 5.5 V C = 30 pF <small>Note 4</small> | | | 25 | | 25 | | 25 | ns |
| | | 1.6 V ≤ E _{VDD0} ≤ 5.5 V C = 30 pF <small>Note 4</small> | | | — | | 25 | | 25 | ns |

- Notes**
1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
 4. C is the load capacitance of the SCKp and SOp output lines.

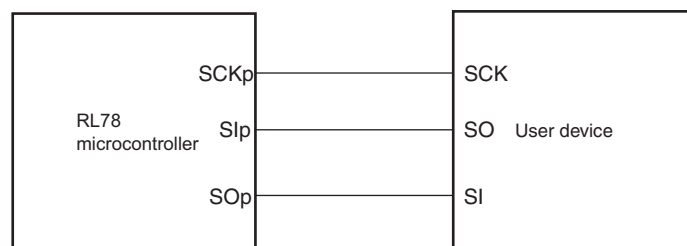
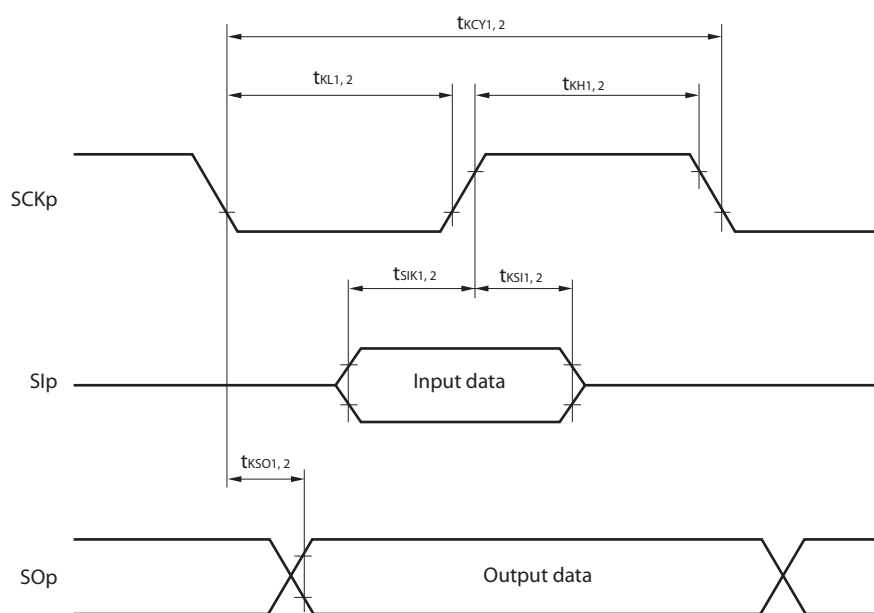
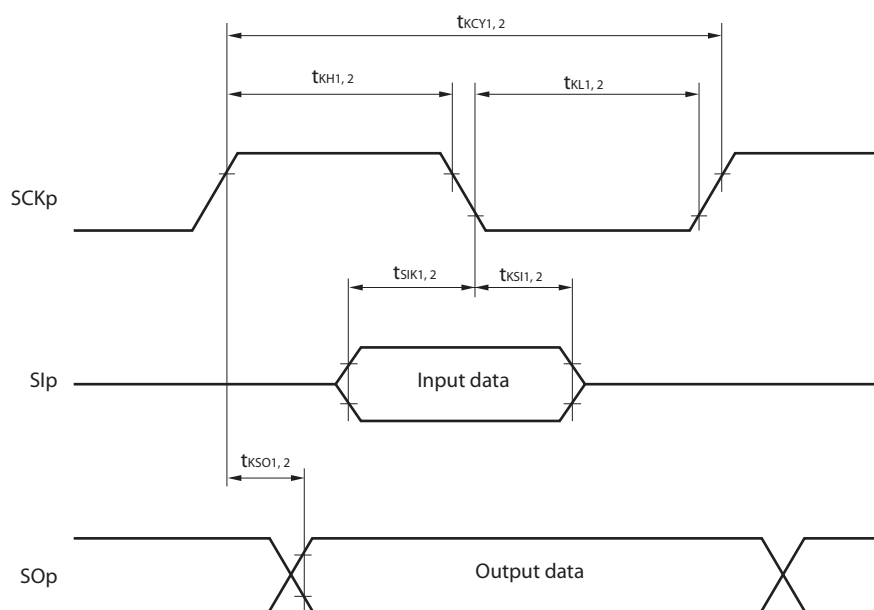
Caution Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),
g: PIM and POM numbers (g = 0, 1, 4, 5, 8, 14)
- 2.** f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,
n: Channel number (mn = 00 to 03, 10 to 13))

(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input) (1/2)
(T_A = -40 to +85°C, 1.6 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V)

| Parameter | Symbol | Conditions | | HS (high-speed main) Mode | | LS (low-speed main) Mode | | LV (low-voltage main) Mode | | Unit |
|--|--|-----------------------------------|---------------------------|--------------------------------|------|--------------------------------|------|--------------------------------|------|------|
| | | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCKp cycle time <small>Note 5</small> | t _{KCY2} | 4.0 V ≤ EV _{DD0} ≤ 5.5 V | 20 MHz < f _{MCK} | 8/f _{MCK} | | — | | — | | ns |
| | | | f _{MCK} ≤ 20 MHz | 6/f _{MCK} | | 6/f _{MCK} | | 6/f _{MCK} | | ns |
| | | 2.7 V ≤ EV _{DD0} ≤ 5.5 V | 16 MHz < f _{MCK} | 8/f _{MCK} | | — | | — | | ns |
| | | | f _{MCK} ≤ 16 MHz | 6/f _{MCK} | | 6/f _{MCK} | | 6/f _{MCK} | | ns |
| | | 2.4 V ≤ EV _{DD0} ≤ 5.5 V | | 6/f _{MCK} and 500 | | 6/f _{MCK} and 500 | | 6/f _{MCK} and 500 | | ns |
| | | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | 6/f _{MCK} and 750 | | 6/f _{MCK} and 750 | | 6/f _{MCK} and 750 | | ns |
| | | 1.7 V ≤ EV _{DD0} ≤ 5.5 V | | 6/f _{MCK} and 1500 | | 6/f _{MCK} and 1500 | | 6/f _{MCK} and 1500 | | ns |
| | | 1.6 V ≤ EV _{DD0} ≤ 5.5 V | | — | | 6/f _{MCK} and 1500 | | 6/f _{MCK} and 1500 | | ns |
| SCKp high-/low-level width | t _{KH2} , t _{KL2} | 4.0 V ≤ EV _{DD0} ≤ 5.5 V | | t _{KCY2} /2 – 7 | | t _{KCY2} /2 – 7 | | t _{KCY2} /2 – 7 | | ns |
| | | 2.7 V ≤ EV _{DD0} ≤ 5.5 V | | t _{KCY2} /2 – 8 | | t _{KCY2} /2 – 8 | | t _{KCY2} /2 – 8 | | ns |
| | | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | t _{KCY2} /2 – 18 | | t _{KCY2} /2 – 18 | | t _{KCY2} /2 – 18 | | ns |
| | | 1.7 V ≤ EV _{DD0} ≤ 5.5 V | | t _{KCY2} /2 – 66 | | t _{KCY2} /2 – 66 | | t _{KCY2} /2 – 66 | | ns |
| | | 1.6 V ≤ EV _{DD0} ≤ 5.5 V | | — | | t _{KCY2} /2 – 66 | | t _{KCY2} /2 – 66 | | ns |

(Notes, Caution, and Remarks are listed on the next page.)

CSI mode connection diagram (during communication at same potential)**CSI mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)****CSI mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**

- Remarks**
1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)
 2. m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)

(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (1/2)**(T_A = -40 to +85°C, 1.8 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V)**

| Parameter | Symbol | Conditions | | HS (high-speed main) Mode | | LS (low-speed main) Mode | | LV (low-voltage main) Mode | | Unit | |
|---|--------|------------|---|---------------------------|-----------------------------------|-------------------------------|-----------------------------------|-------------------------------|------|-------------------------------|------|
| | | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | | |
| Transfer rate | | Reception | 4.0 V ≤ EV _{DD0} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | | | f _{MCK} /6 Note 1 | | f _{MCK} /6 Note 1 | | f _{MCK} /6 Note 1 | bps |
| | | | | | | 5.3 | | 1.3 | | 0.6 | Mbps |
| | | | Theoretical value of the maximum transfer rate f _{MCK} = f _{CLK} ^{Note 4} | | | | | | | | |
| | | | | | | 5.3 | | 1.3 | | 0.6 | Mbps |
| | | | 2.7 V ≤ EV _{DD0} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | | | f _{MCK} /6 Note 1 | | f _{MCK} /6 Note 1 | | f _{MCK} /6 Note 1 | bps |
| | | | | | | 5.3 | | 1.3 | | 0.6 | Mbps |
| 1.8 V ≤ EV _{DD0} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | | | f _{MCK} /6 Notes 1 to 3 | | f _{MCK} /6 Notes 1, 2 | | f _{MCK} /6 Notes 1, 2 | bps | | | |
| | | | 5.3 | | 1.3 | | 0.6 | Mbps | | | |
| Theoretical value of the maximum transfer rate f _{MCK} = f _{CLK} ^{Note 4} | | | | | | | | | | | |
| | | | | | | | | | | | |

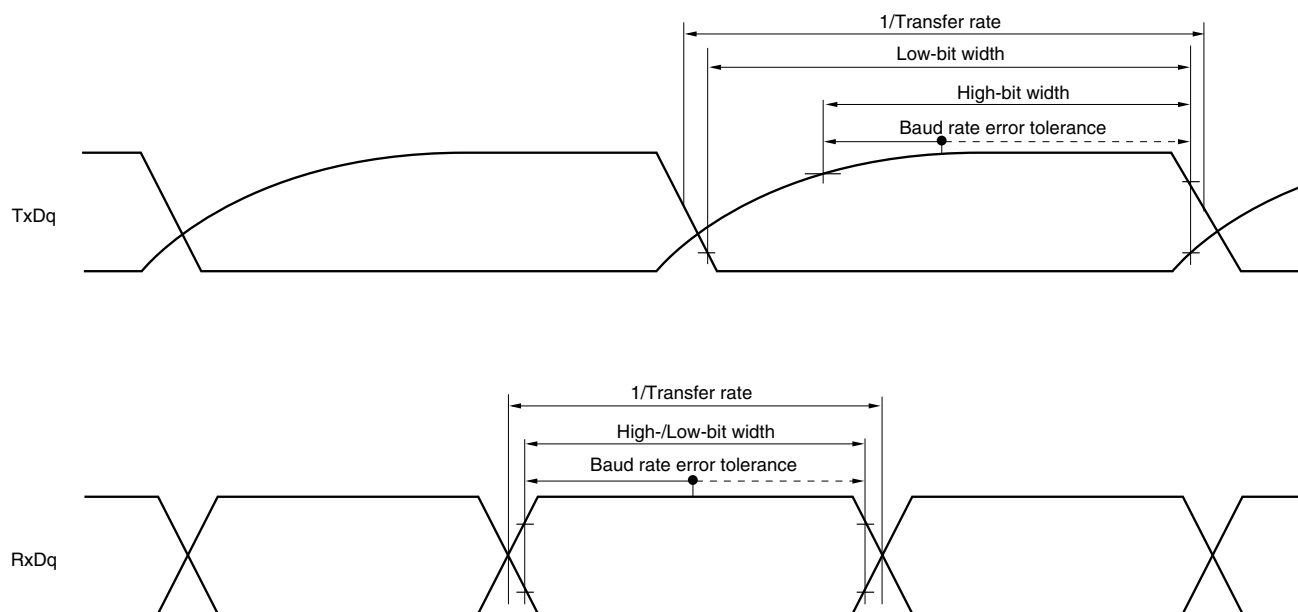
Notes 1. Transfer rate in the SNOOZE mode is 4800 bps only.**2.** Use it with EV_{DD0} ≥ V_b.**3.** The following conditions are required for low voltage interface when EV_{DD0} < V_{DD}.2.4 V ≤ EV_{DD0} < 2.7 V : MAX. 2.6 Mbps1.8 V ≤ EV_{DD0} < 2.4 V : MAX. 1.3 Mbps**4.** The maximum operating frequencies of the CPU/peripheral hardware clock (f_{CLK}) are:HS (high-speed main) mode: 32 MHz (2.7 V ≤ V_{DD} ≤ 5.5 V)16 MHz (2.4 V ≤ V_{DD} ≤ 5.5 V)LS (low-speed main) mode: 8 MHz (1.8 V ≤ V_{DD} ≤ 5.5 V)LV (low-voltage main) mode: 4 MHz (1.6 V ≤ V_{DD} ≤ 5.5 V)

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance (When 20- to 52-pin products)/EV_{DD} tolerance (When 64- to 128-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

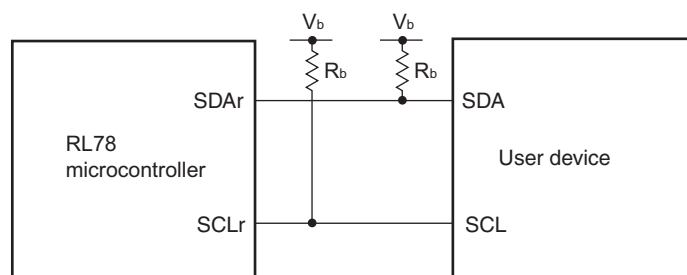
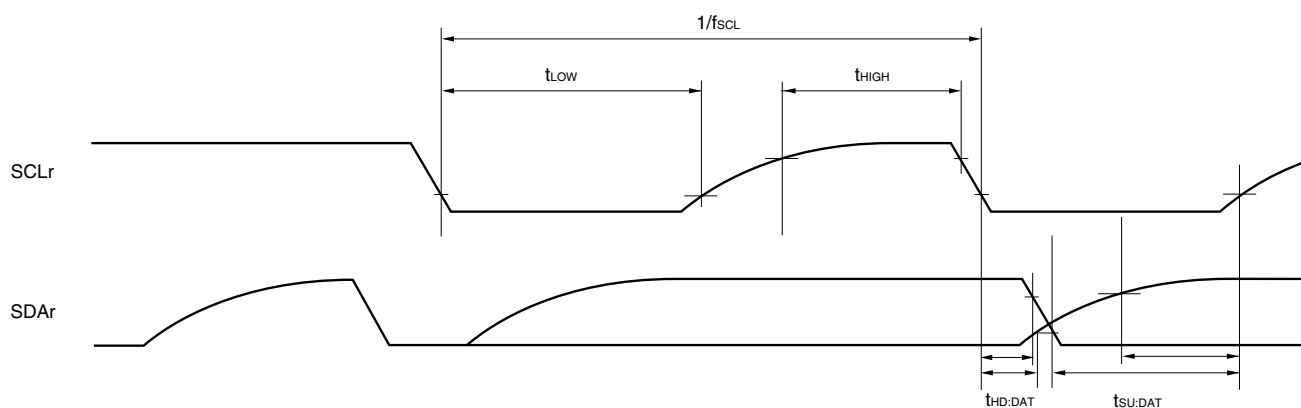
Remarks 1. V_b[V]: Communication line voltage**2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)**3.** f_{MCK}: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

4. UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

UART mode bit width (during communication at different potential) (reference)

- Remarks**
1. $R_b[\Omega]$: Communication line (TxDq) pull-up resistance,
 $C_b[\text{F}]$: Communication line (TxDq) load capacitance, $V_b[\text{V}]$: Communication line voltage
 2. q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)
 3. f_{MCK} : Serial array unit operation clock frequency
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
 m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))
 4. UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

Simplified I²C mode connection diagram (during communication at different potential)**Simplified I²C mode serial transfer timing (during communication at different potential)**

- Remarks**
1. $R_b[\Omega]$: Communication line (SDAr, SCLr) pull-up resistance, $C_b[F]$: Communication line (SDAr, SCLr) load capacitance, $V_b[V]$: Communication line voltage
 2. r: IIC number (r = 00, 01, 10, 20, 30, 31), g: PIM, POM number (g = 0, 1, 4, 5, 8, 14)
 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13))

2.6.4 LVD circuit characteristics

LVD Detection Voltage of Reset Mode and Interrupt Mode(T_A = -40 to +85°C, V_{PDR} ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------|----------------------|--------------------|------------------------|------|------|------|------|
| Detection voltage | Supply voltage level | V _{LVD0} | Power supply rise time | 3.98 | 4.06 | 4.14 | V |
| | | | Power supply fall time | 3.90 | 3.98 | 4.06 | V |
| | | V _{LVD1} | Power supply rise time | 3.68 | 3.75 | 3.82 | V |
| | | | Power supply fall time | 3.60 | 3.67 | 3.74 | V |
| | | V _{LVD2} | Power supply rise time | 3.07 | 3.13 | 3.19 | V |
| | | | Power supply fall time | 3.00 | 3.06 | 3.12 | V |
| | | V _{LVD3} | Power supply rise time | 2.96 | 3.02 | 3.08 | V |
| | | | Power supply fall time | 2.90 | 2.96 | 3.02 | V |
| | | V _{LVD4} | Power supply rise time | 2.86 | 2.92 | 2.97 | V |
| | | | Power supply fall time | 2.80 | 2.86 | 2.91 | V |
| | | V _{LVD5} | Power supply rise time | 2.76 | 2.81 | 2.87 | V |
| | | | Power supply fall time | 2.70 | 2.75 | 2.81 | V |
| | | V _{LVD6} | Power supply rise time | 2.66 | 2.71 | 2.76 | V |
| | | | Power supply fall time | 2.60 | 2.65 | 2.70 | V |
| | | V _{LVD7} | Power supply rise time | 2.56 | 2.61 | 2.66 | V |
| | | | Power supply fall time | 2.50 | 2.55 | 2.60 | V |
| | | V _{LVD8} | Power supply rise time | 2.45 | 2.50 | 2.55 | V |
| | | | Power supply fall time | 2.40 | 2.45 | 2.50 | V |
| | | V _{LVD9} | Power supply rise time | 2.05 | 2.09 | 2.13 | V |
| | | | Power supply fall time | 2.00 | 2.04 | 2.08 | V |
| | | V _{LVD10} | Power supply rise time | 1.94 | 1.98 | 2.02 | V |
| | | | Power supply fall time | 1.90 | 1.94 | 1.98 | V |
| | | V _{LVD11} | Power supply rise time | 1.84 | 1.88 | 1.91 | V |
| | | | Power supply fall time | 1.80 | 1.84 | 1.87 | V |
| | | V _{LVD12} | Power supply rise time | 1.74 | 1.77 | 1.81 | V |
| | | | Power supply fall time | 1.70 | 1.73 | 1.77 | V |
| | | V _{LVD13} | Power supply rise time | 1.64 | 1.67 | 1.70 | V |
| | | | Power supply fall time | 1.60 | 1.63 | 1.66 | V |
| Minimum pulse width | | t _{LW} | | 300 | | | μs |
| Detection delay time | | | | | | 300 | μs |

3. ELECTRICAL SPECIFICATIONS (G: INDUSTRIAL APPLICATIONS $T_A = -40$ to $+105^\circ\text{C}$)

This chapter describes the following electrical specifications.

Target products G: Industrial applications $T_A = -40$ to $+105^\circ\text{C}$
R5F100xxGxx

- Cautions**
1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
 2. With products not provided with an EV_{DD0} , EV_{DD1} , EV_{SS0} , or EV_{SS1} pin, replace EV_{DD0} and EV_{DD1} with V_{DD} , or replace EV_{SS0} and EV_{SS1} with V_{SS} .
 3. The pins mounted depend on the product. Refer to 2.1 Port Function to 2.2.1 Functions for each product.
 4. Please contact Renesas Electronics sales office for derating of operation under $T_A = +85^\circ\text{C}$ to $+105^\circ\text{C}$. Derating is the systematic reduction of load for the sake of improved reliability.

Remark When RL78/G13 is used in the range of $T_A = -40$ to $+85^\circ\text{C}$, see **CHAPTER 2 ELECTRICAL SPECIFICATIONS ($T_A = -40$ to $+85^\circ\text{C}$)**.

There are following differences between the products "G: Industrial applications ($T_A = -40$ to $+105^\circ\text{C}$)" and the products "A: Consumer applications, and D: Industrial applications".

| Parameter | Application | |
|--|--|--|
| | A: Consumer applications, D: Industrial applications | G: Industrial applications |
| Operating ambient temperature | $T_A = -40$ to $+85^\circ\text{C}$ | $T_A = -40$ to $+105^\circ\text{C}$ |
| Operating mode Operating voltage range | HS (high-speed main) mode: $2.7\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$ $2.4\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$ LS (low-speed main) mode: $1.8\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}@1\text{ MHz to }8\text{ MHz}$ LV (low-voltage main) mode: $1.6\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}@1\text{ MHz to }4\text{ MHz}$ | HS (high-speed main) mode only: $2.7\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$ $2.4\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$ |
| High-speed on-chip oscillator clock accuracy | $1.8\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$ $\pm 1.0\% @ T_A = -20$ to $+85^\circ\text{C}$ $\pm 1.5\% @ T_A = -40$ to -20°C $1.6\text{ V} \leq V_{\text{DD}} < 1.8\text{ V}$ $\pm 5.0\% @ T_A = -20$ to $+85^\circ\text{C}$ $\pm 5.5\% @ T_A = -40$ to -20°C | $2.4\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$ $\pm 2.0\% @ T_A = +85$ to $+105^\circ\text{C}$ $\pm 1.0\% @ T_A = -20$ to $+85^\circ\text{C}$ $\pm 1.5\% @ T_A = -40$ to -20°C |
| Serial array unit | UART CSI: $f_{\text{CLK}}/2$ (supporting 16 Mbps), $f_{\text{CLK}}/4$ Simplified I ² C communication | UART CSI: $f_{\text{CLK}}/4$ Simplified I ² C communication |
| IICA | Normal mode Fast mode Fast mode plus | Normal mode Fast mode |
| Voltage detector | Rise detection voltage: 1.67 V to 4.06 V (14 levels) Fall detection voltage: 1.63 V to 3.98 V (14 levels) | Rise detection voltage: 2.61 V to 4.06 V (8 levels) Fall detection voltage: 2.55 V to 3.98 V (8 levels) |

(Remark is listed on the next page.)

($T_A = -40$ to $+105^\circ\text{C}$, $2.4\text{ V} \leq \text{EV}_{\text{DD0}} = \text{EV}_{\text{DD1}} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$, $\text{V}_{\text{SS}} = \text{EV}_{\text{SS0}} = \text{EV}_{\text{SS1}} = 0\text{ V}$) (4/5)

| Items | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------|-------------------------|--|---|--------------------------------|------|------|
| Output voltage, high | V_{OH1} | P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147 | $4.0\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OH1}} = -3.0\text{ mA}$ | $\text{EV}_{\text{DD0}} - 0.7$ | | V |
| | | | $2.7\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OH1}} = -2.0\text{ mA}$ | $\text{EV}_{\text{DD0}} - 0.6$ | | V |
| | | | $2.4\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OH1}} = -1.5\text{ mA}$ | $\text{EV}_{\text{DD0}} - 0.5$ | | V |
| | V_{OH2} | P20 to P27, P150 to P156 | $2.4\text{ V} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$, $\text{I}_{\text{OH2}} = -100\text{ }\mu\text{A}$ | $\text{V}_{\text{DD}} - 0.5$ | | V |
| Output voltage, low | V_{OL1} | P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147 | $4.0\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL1}} = 8.5\text{ mA}$ | | 0.7 | V |
| | | | $4.0\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL1}} = 3.0\text{ mA}$ | | 0.6 | V |
| | | | $2.7\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL1}} = 1.5\text{ mA}$ | | 0.4 | V |
| | | | $2.4\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL1}} = 0.6\text{ mA}$ | | 0.4 | V |
| | V_{OL2} | P20 to P27, P150 to P156 | $2.4\text{ V} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL2}} = 400\text{ }\mu\text{A}$ | | 0.4 | V |
| | V_{OL3} | P60 to P63 | $4.0\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL3}} = 15.0\text{ mA}$ | | 2.0 | V |
| | | | $4.0\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL3}} = 5.0\text{ mA}$ | | 0.4 | V |
| | | | $2.7\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL3}} = 3.0\text{ mA}$ | | 0.4 | V |
| | | | $2.4\text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5\text{ V}$, $\text{I}_{\text{OL3}} = 2.0\text{ mA}$ | | 0.4 | V |

Caution P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

- Notes**
1. Total current flowing into V_{DD} , EV_{DD0} , and EV_{DD1} , including the input leakage current flowing when the level of the input pin is fixed to V_{DD} , EV_{DD0} , and EV_{DD1} , or V_{SS} , EV_{SS0} , and EV_{SS1} . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
 2. During HALT instruction execution by flash memory.
 3. When high-speed on-chip oscillator and subsystem clock are stopped.
 4. When high-speed system clock and subsystem clock are stopped.
 5. When high-speed on-chip oscillator and high-speed system clock are stopped. When $RTCLPC = 1$ and setting ultra-low current consumption ($AMPHS1 = 1$). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
 6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
 7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode: $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$

8. Regarding the value for current operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks**
1. f_{MX} : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
 2. f_{IH} : High-speed on-chip oscillator clock frequency
 3. f_{SUB} : Subsystem clock frequency (XT1 clock oscillation frequency)
 4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is $T_A = 25^{\circ}\text{C}$

(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)

 $(T_A = -40 \text{ to } +105^\circ\text{C}, 2.4 \text{ V} \leq \text{EV}_{\text{DD0}} = \text{EV}_{\text{DD1}} \leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}, \text{V}_{\text{SS}} = \text{EV}_{\text{SS0}} = \text{EV}_{\text{SS1}} = 0 \text{ V})$

| Parameter | Symbol | Conditions | HS (high-speed main) Mode | | Unit |
|---|----------------------------------|--|---------------------------|------|------|
| | | | MIN. | MAX. | |
| SCKp cycle time | t_{KCY1} | $t_{\text{KCY1}} \geq 4/f_{\text{CLK}}$ | 250 | | ns |
| | | $2.4 \text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5 \text{ V}$ | 500 | | ns |
| SCKp high-/low-level width | $t_{\text{KH1}}, t_{\text{KL1}}$ | $4.0 \text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5 \text{ V}$ | $t_{\text{KCY1}}/2 - 24$ | | ns |
| | | $2.7 \text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5 \text{ V}$ | $t_{\text{KCY1}}/2 - 36$ | | ns |
| | | $2.4 \text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5 \text{ V}$ | $t_{\text{KCY1}}/2 - 76$ | | ns |
| Slp setup time (to SCKp \uparrow) ^{Note 1} | t_{SIK1} | $4.0 \text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5 \text{ V}$ | 66 | | ns |
| | | $2.7 \text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5 \text{ V}$ | 66 | | ns |
| | | $2.4 \text{ V} \leq \text{EV}_{\text{DD0}} \leq 5.5 \text{ V}$ | 113 | | ns |
| Slp hold time (from SCKp \uparrow) ^{Note 2} | t_{KSI1} | | 38 | | ns |
| Delay time from SCKp \downarrow to SOp output ^{Note 3} | t_{KSO1} | $C = 30 \text{ pF}$ ^{Note 4} | | 50 | ns |

- Notes**
1. When $\text{DAPmn} = 0$ and $\text{CKPmn} = 0$, or $\text{DAPmn} = 1$ and $\text{CKPmn} = 1$. The Slp setup time becomes “to SCKp \downarrow ” when $\text{DAPmn} = 0$ and $\text{CKPmn} = 1$, or $\text{DAPmn} = 1$ and $\text{CKPmn} = 0$.
 2. When $\text{DAPmn} = 0$ and $\text{CKPmn} = 0$, or $\text{DAPmn} = 1$ and $\text{CKPmn} = 1$. The Slp hold time becomes “from SCKp \downarrow ” when $\text{DAPmn} = 0$ and $\text{CKPmn} = 1$, or $\text{DAPmn} = 1$ and $\text{CKPmn} = 0$.
 3. When $\text{DAPmn} = 0$ and $\text{CKPmn} = 0$, or $\text{DAPmn} = 1$ and $\text{CKPmn} = 1$. The delay time to SOp output becomes “from SCKp \uparrow ” when $\text{DAPmn} = 0$ and $\text{CKPmn} = 1$, or $\text{DAPmn} = 1$ and $\text{CKPmn} = 0$.
 4. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

- Remarks**
1. p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),
g: PIM and POM numbers (g = 0, 1, 4, 5, 8, 14)
 2. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (2/2)

(T_A = -40 to +105°C, 2.4 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V)

| Parameter | Symbol | Conditions | HS (high-speed main) Mode | | Unit |
|---------------|--------|--------------|---|------------------------|------|
| | | | MIN. | MAX. | |
| Transfer rate | | Transmission | 4.0 V ≤ EV _{DD0} ≤ 5.5 V, | | |
| | | | 2.7 V ≤ V _b ≤ 4.0 V | | |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 1.4 kΩ, V _b = 2.7 V | | |
| | | | | Note 1 | bps |
| | | | | 2.6 ^{Note 2} | Mbps |
| | | | | | |
| | | | 2.7 V ≤ EV _{DD0} < 4.0 V, | | |
| | | | 2.3 V ≤ V _b ≤ 2.7 V | | |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 2.7 kΩ, V _b = 2.3 V | | |
| | | | | Note 3 | bps |
| | | | | 1.2 ^{Note 4} | Mbps |
| | | | | | |
| | | | 2.4 V ≤ EV _{DD0} < 3.3 V, | | |
| | | | 1.6 V ≤ V _b ≤ 2.0 V | | |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 5.5 kΩ, V _b = 1.6 V | | |
| | | | | Note 5 | bps |
| | | | | 0.43 ^{Note 6} | Mbps |

Notes 1. The smaller maximum transfer rate derived by using f_{MCK}/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ EV_{DD0} ≤ 5.5 V and 2.7 V ≤ V_b ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

- This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.
- The smaller maximum transfer rate derived by using f_{MCK}/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ EV_{DD0} < 4.0 V and 2.4 V ≤ V_b ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

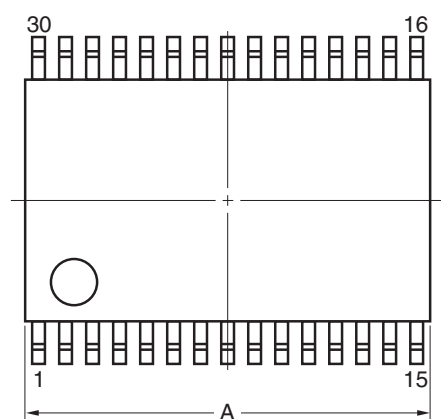
* This value is the theoretical value of the relative difference between the transmission and reception sides.

- This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 3 above to calculate the maximum transfer rate under conditions of the customer.

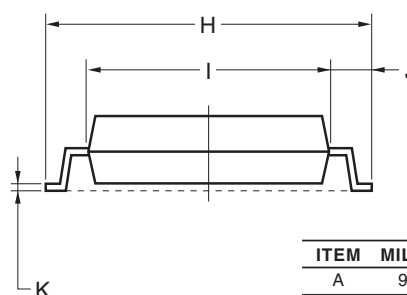
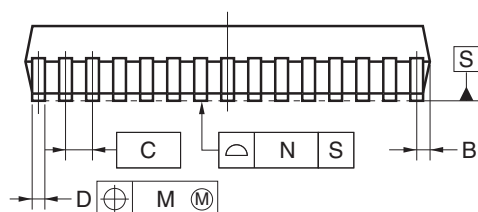
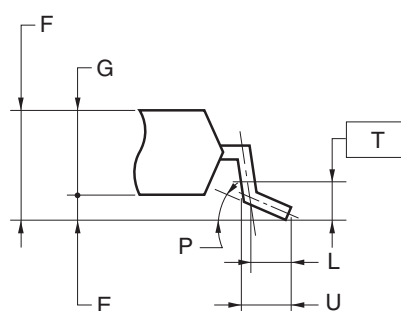
4.4 30-pin Products

R5F100AAASP, R5F100ACASP, R5F100ADASP, R5F100AEASP, R5F100AFASP, R5F100AGASP
 R5F101AAASP, R5F101ACASP, R5F101ADASP, R5F101AEASP, R5F101AFASP, R5F101AGASP
 R5F100AADSP, R5F100ACDSP, R5F100ADDSP, R5F100AEDSP, R5F100AFDSP, R5F100AGDSP
 R5F101AADSP, R5F101ACDSP, R5F101ADDSP, R5F101AEDSP, R5F101AFDSP, R5F101AGDSP
 R5F100AAGSP, R5F100ACGSP, R5F100ADGSP, R5F100AEGSP, R5F100AFGSP, R5F100AGGSP

| JEITA Package Code | RENESAS Code | Previous Code | MASS (TYP.) [g] |
|---------------------|--------------|----------------|-----------------|
| P-LSSOP30-0300-0.65 | PLSP0030JB-B | S30MC-65-5A4-3 | 0.18 |



detail of lead end

**NOTE**

Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS |
|------|--|
| A | 9.85±0.15 |
| B | 0.45 MAX. |
| C | 0.65 (T.P.) |
| D | 0.24 ^{+0.08} _{-0.07} |
| E | 0.1±0.05 |
| F | 1.3±0.1 |
| G | 1.2 |
| H | 8.1±0.2 |
| I | 6.1±0.2 |
| J | 1.0±0.2 |
| K | 0.17±0.03 |
| L | 0.5 |
| M | 0.13 |
| N | 0.10 |
| P | 3° ^{+5°} _{-3°} |
| T | 0.25 |
| U | 0.6±0.15 |